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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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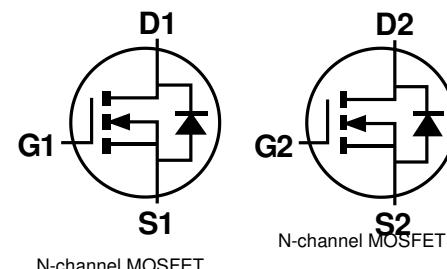
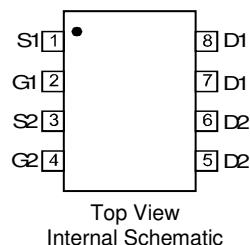
Product Summary

BV_{DSS}	$R_{DS(ON)} \text{ max}$	$I_D \text{ max}$ $T_A = +25^\circ\text{C}$
30V	20m Ω @ $V_{GS} = 10\text{V}$	6.9A
	27m Ω @ $V_{GS} = 4.5\text{V}$	5.8A

Description

This MOSFET is designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters



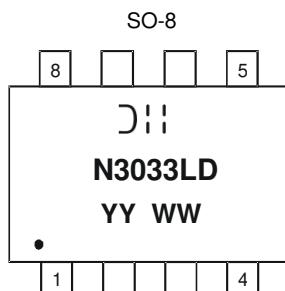
Ordering Information (Note 5)

Part Number	Case	Packaging
DMN3033LSDQ-13	SO-8	2,500/Tape & Reel

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_grade_definitions/.
5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



DII = Manufacturer's Marking
 N3033LD = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Year (ex: 13 = 2013)
 WW = Week (01 - 53)

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Drain-Source Voltage		V_{DSS}	30	V
Gate-Source Voltage		V_{GSS}	± 20	V
Drain Current (Note 6)	Steady State	I_D	6.9 5.8	A
Pulsed Drain Current (Note 7)		I_{DM}	30	A

Thermal Characteristics

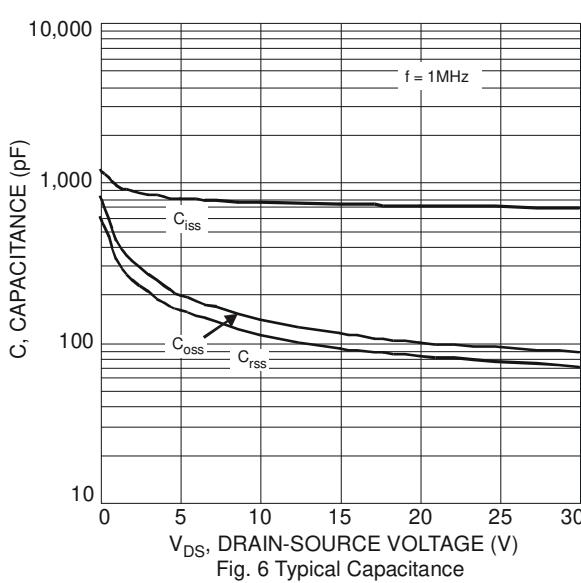
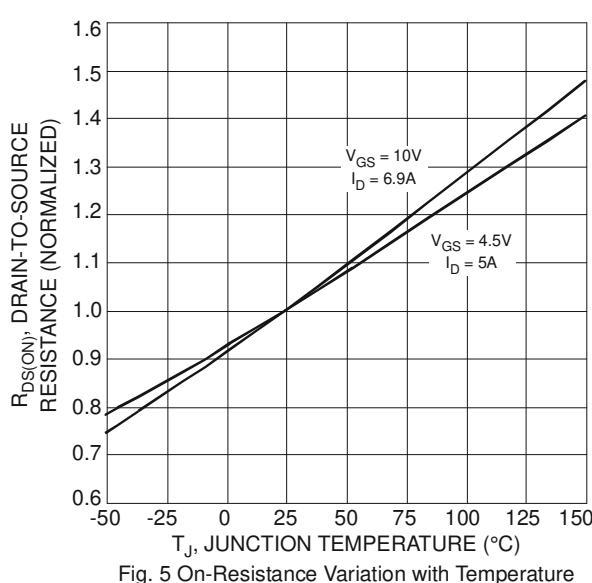
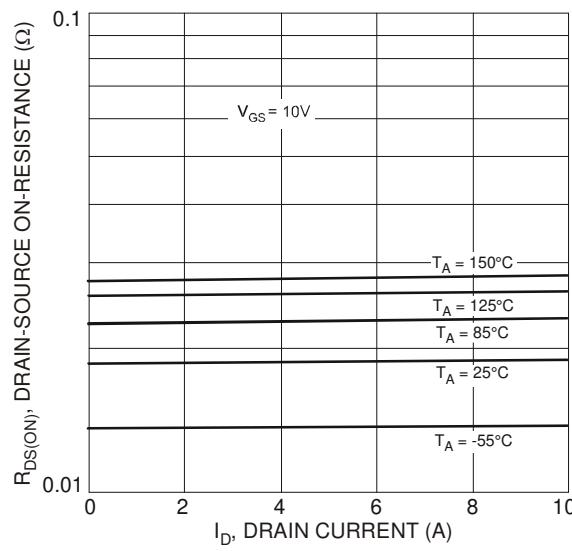
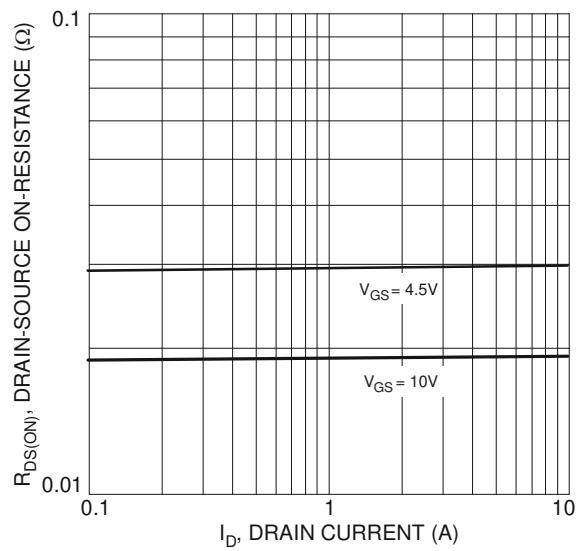
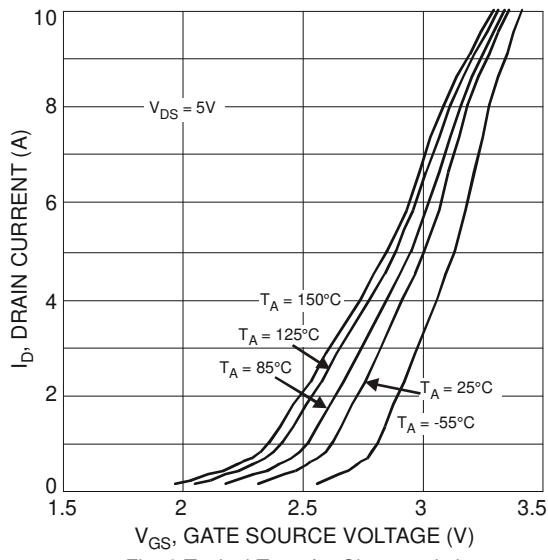
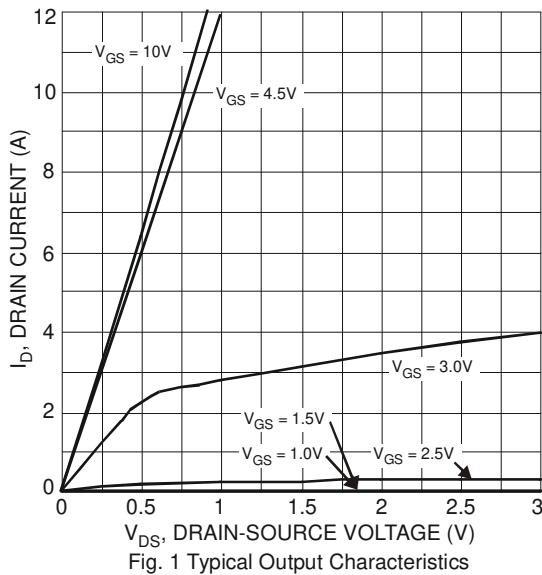
Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P_D	2	W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

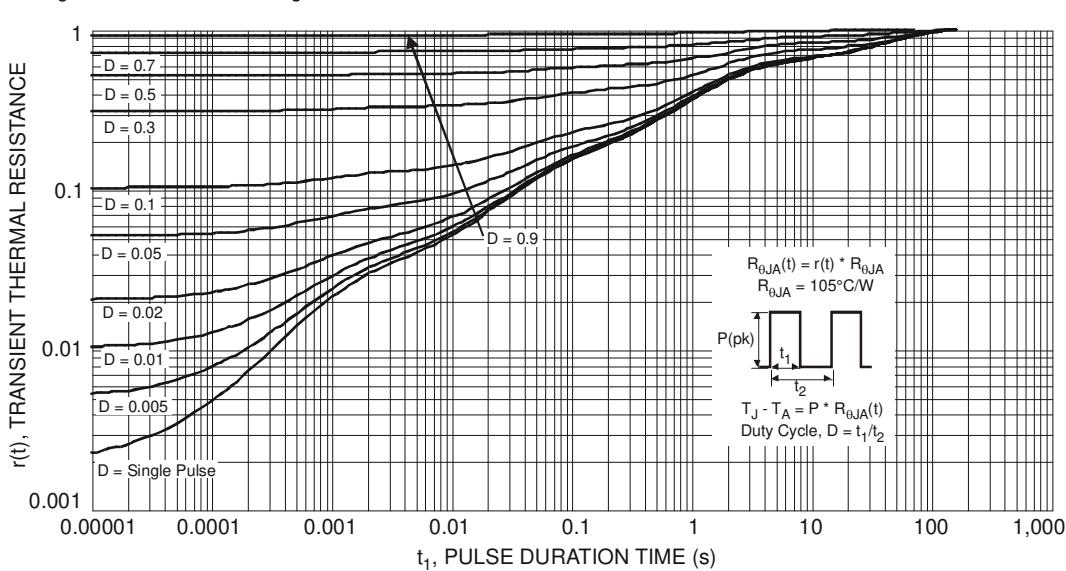
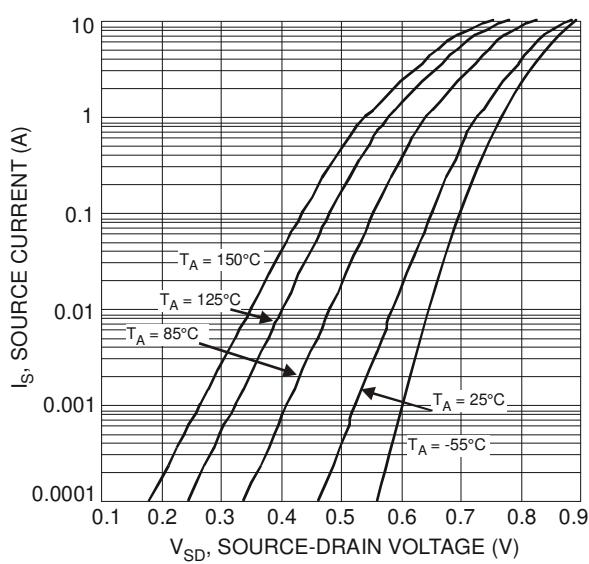
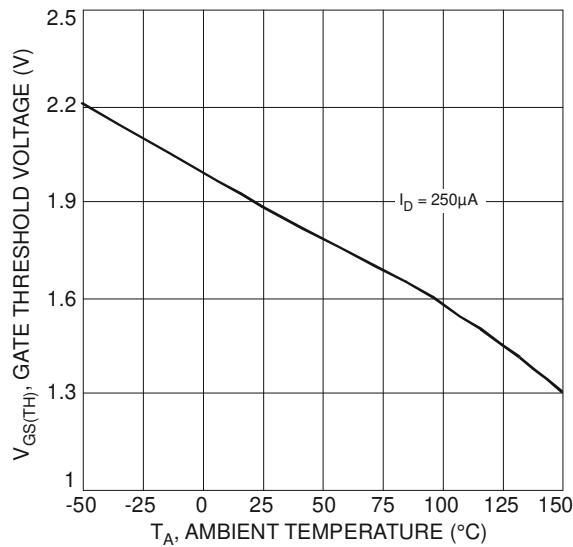
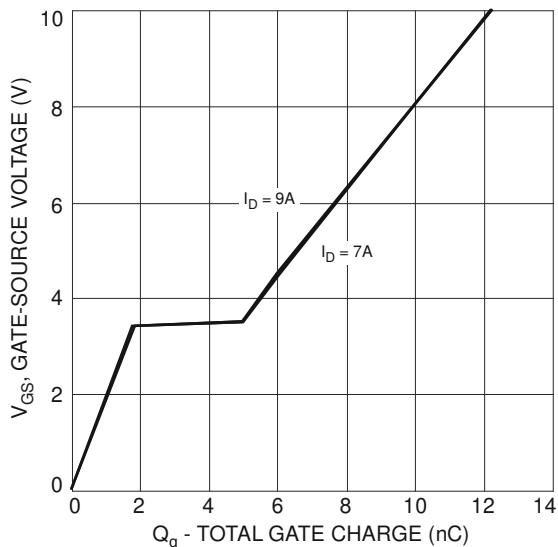
Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV_{DSS}	30	—	—	V	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$
Zero Gate Voltage Drain Current	I_{DSS}	—	—	100	nA	$V_{DS} = 30\text{V}, V_{GS} = 0\text{V}$
Gate-Source Leakage	I_{GSS}	—	—	± 100	nA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
		—	—	1	μA	$V_{GS} = \pm 25\text{V}, V_{DS} = 0\text{V}$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	$V_{GS(\text{th})}$	1	—	2.1	V	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(\text{ON})}$	—	13 22	20 27	$\text{m}\Omega$	$V_{GS} = 10\text{V}, I_D = 6.9\text{A}$ $V_{GS} = 4.5\text{V}, I_D = 5\text{A}$
Forward Transconductance	g_{fs}	—	7	—	S	$V_{DS} = 5\text{V}, I_D = 6.9\text{A}$
Diode Forward Voltage (Note 8)	V_{SD}	0.5	—	1.2	V	$V_{GS} = 0\text{V}, I_S = 1\text{A}$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C_{iss}	—	725	—	pF	$V_{DS} = 15\text{V}, V_{GS} = 0\text{V}$ $f = 1\text{MHz}$
Output Capacitance	C_{oss}	—	114	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	92	—	pF	
Gate Resistance	R_G	—	0.89	—	Ω	$V_{GS} = 0\text{V}, V_{DS} = 0\text{V}, f = 1\text{MHz}$
SWITCHING CHARACTERISTICS (Note 9)						
Total Gate Charge	Q_g	—	6.4 13	—	nC	$V_{GS} = 4.5\text{V}, V_{DS} = 15\text{V}, I_D = 5\text{A}$ $V_{GS} = 10\text{V}, V_{DS} = 15\text{V}, I_D = 6.9\text{A}$
Gate-Source Charge	Q_{gs}	—	1.9	—	nC	$V_{GS} = 4.5\text{V}, V_{DS} = 15\text{V}, I_D = 6.9\text{A}$
Gate-Drain Charge	Q_{gd}	—	3.2	—	nC	$V_{GS} = 4.5\text{V}, V_{DS} = 15\text{V}, I_D = 6.9\text{A}$
Turn-On Delay Time	$t_{d(on)}$	—	11	—	ns	$V_{DD} = 15\text{V}, V_{GS} = 10\text{V},$ $R_D = 1.8\Omega, R_G = 6\Omega$
Turn-On Rise Time	t_r	—	7	—	ns	
Turn-Off Delay Time	$t_{d(off)}$	—	63	—	ns	
Turn-Off Fall Time	t_f	—	30	—	ns	

Notes:

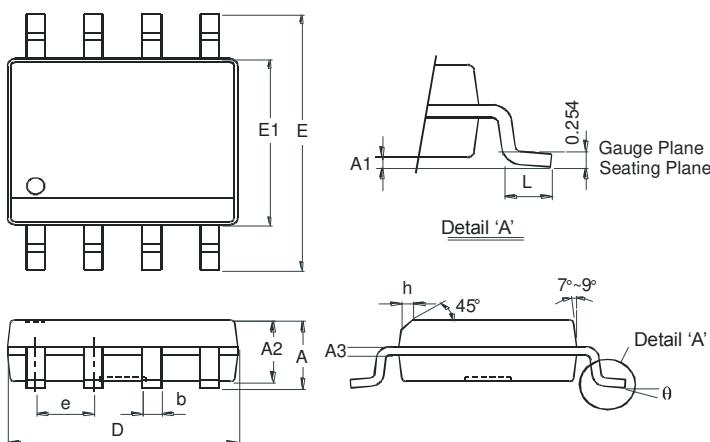
6. Device mounted on 2 oz. Copper pads on FR-4 PCB with $R_{\theta JA} = 62.5\text{^\circ C/W}$.
7. Pulse width $\leq 10\mu\text{s}$, Duty Cycle $\leq 1\%$.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.





Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

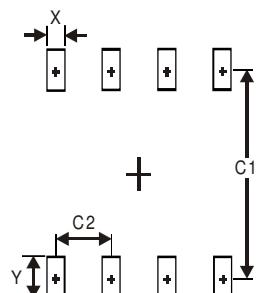


SO-8		
Dim	Min	Max
A	-	1.75
A1	0.10	0.20
A2	1.30	1.50
A3	0.15	0.25
b	0.3	0.5
D	4.85	4.95
E	5.90	6.10
E1	3.85	3.95
e	1.27 Typ	
h	-	0.35
L	0.62	0.82
θ	0°	8°

All Dimensions in mm

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27

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